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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/728,562	12/05/2003	Robert R. Alfano	5250-7	8886
7590 04/18/2005		EXAMINER		
Kent H. Cheng, Esq.			JACKSON JR, JEROME	
Cohen, Pontani, Lieberman & Pavane Suite 1210			ART UNIT	PAPER NUMBER
551 Fifth Avenue			2815	
New York, NY 10176			DATE MAILED: 04/18/2005	

Please find below and/or attached an Office communication concerning this application or proceeding.

1) Notice of References Cited (PTO-892)

Paper No(s)/Mail Date 12/5/03.

2) Notice of Draftsperson's Patent Drawing Review (PTO-948)

3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)

4) Interview Summary (PTO-413)
Paper No(s)/Mail Date. _____.

6) ___ Other:

5) Notice of Informal Patent Application (PTO-152)

Attachment(s)

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The drawings are objected to because figures 3 and 8 are obscure. Corrected drawing sheets in compliance with 37 CFR 1.121(d) are required in reply to the Office action to avoid abandonment of the application. Any amended replacement drawing sheet should include all of the figures appearing on the immediate prior version of the sheet, even if only one figure is being amended. The figure or figure number of an amended drawing should not be labeled as "amended." If a drawing figure is to be canceled, the appropriate figure must be removed from the replacement sheet, and where necessary, the remaining figures must be renumbered and appropriate changes made to the brief description of the several views of the drawings for consistency. Additional replacement sheets may be necessary to show the renumbering of the remaining figures. Each drawing sheet submitted after the filing date of an application must be labeled in the top margin as either "Replacement Sheet" or "New Sheet" pursuant to 37 CFR 1.121(d). If the changes are not accepted by the examiner, the applicant will be notified and informed of any required corrective action in the next Office action. The objection to the drawings will not be held in abeyance.

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States

only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 1-12,15,16,19-30 are rejected under 35 U.S.C. 102(e) as being anticipated by Wang '060.

Wang teaches a resonant tunneling light emitter comprising a sapphire substrate, p and n AlGaN layers, two intrinsic quantum wells, and ohmic contacts. See figure 1. Claims 1-11,15 are anticipated. Claim 12 is rejected as multiple quantum wells can be substituted for a single quantum well embodiment, column 3 lines 35-45. Claims 16 and 20-30 are rejected as the functional language does not structurally distinguish the claims over Wang which can function in the same manner. Claim 19 is rejected as the wells would be one or the other.

Claims 1-30 are rejected under 35 U.S.C. 103(a) as being unpatentable over Wang, above.

In regard to claims 13,14,17 and 18, the alternate embodiment comprising MQW typically would comprises same thickness barriers and same material. See the text in column 3. The layers are also semi-insulating as they are not doped.

Claims 1-30 are rejected under 35 U.S.C. 103(a) as being unpatentable over Raisky et al APL 7/01 in view of Cho '675.

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Raisky teaches a room temperature p-I-n photovoltaic structure comprising InGaAsP/InP materials that absorb at particular wavelengths. The difference between the claims and Raisky is GaN based material. This difference is not patentable because Cho teaches the GaN based material system for its increased conduction band offset and response at more desirable wavelength ranges. Accordingly it would have been obvious to have practiced a p-l-n photovoltaic resonant tunneling structure with GaN based materials from the suggested teachings of Raisky and Cho. Claim 1 does not recited any particular quantum well thicknesses or exact doping levels or material stoichiometry which could distinguish over the wavelength detection suggestions of Cho and accordingly is considered prima facie obvious. Claim 2 is rejected as the applied art suggests p-type GaN or AlGaN material for ohmic contact to apply a necessary voltage. Claim 3 is rejected as the applied art suggests quantum wells and barriers of similar number, for example, Raisky teaches 21 periods of wells and barriers. Claim 4 is rejected as Raisky teaches a single n-doped layer and Cho teaches a single layer or multiple doped layers. Claim 5 is likewise rejected. Claim 6 is rejected as Cho teaches similar doping levels to populate the wells and Raisky teaches doped contact layers which ordinarily would have high doping to ensure ohmic contact. Claim 7 is rejected as the n-ohmic contact layer is 0.1um. Claims 8-15 are rejected as the prior art shows similar structure and there is no particularly claimed structure which would distinguish over Cho or Raisky. Claim 16 is rejected as Cho teaches large band offset and the claimed formula merely describes the function of Cho, Raisky, or applicant's device. Claims 17 is rejected as undoped well and barriers from Raisky are "semi-insulating".

There are no particularly claimed dopant levels or resistance values. Claim 18 is rejected as above. Claim 19 is rejected as the well/barrier structure of Cho (or Raisky) must necessarily be one or another of the recited structure. Claim 20 recites a broad array of materials which encompasses the materials of Cho. Claim 21-27 are rejected as the functional language does not structurally distinguish the claims over the applied art. Claim 28 is rejected as the p and n type ohmic contact layers of Raisky have a larger bandgap than the I type region and the functional language merely describes the operation of a Raisky with Cho type device. Claim 29 is rejected as Cho teaches absorption in these regions. Claim 30 is rejected as Cho teaches the device as an infrared emitter.

Claims 31-35 are allowed.

These claims recite specific structure that is not fairly suggested by the applied art.

Razeghi '324 and Schaff '003 are relevant art.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Jerome Jackson Jr. whose telephone number is 571 272 1730. The examiner can normally be reached on t-th 9-5.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Tom Thomas can be reached on 571 272 1664. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

ij.

JEROME JACKSON PRIMARY EXAMINER